

N-CHANNEL MOS FIELD EFFECT TRANSISTOR
FOR HIGH SPEED SWITCHING

DESCRIPTION

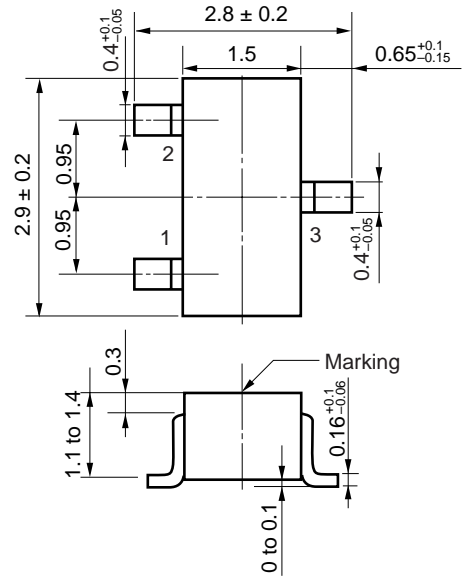
The 2SK1399 is an N-channel vertical type MOS FET which can be driven by 2.5-V power supply.

The 2SK1399 is driven by low voltage and does not require consideration of driving current, it is suitable for appliances including VCR cameras and headphone stereos which need power saving.

FEATURES

- Can be driven by a 3.0-V power source
- Not necessary to consider driving current because of it is high input impedance
- Possible to reduce the number of parts by omitting the bias resistor
- Can be used complementary with the 2SJ185

PACKAGE DRAWING (Unit : mm)



ORDERING INFORMATION

PART NUMBER	PACKAGE
2SK1399	SC-59 (Mini Mold)

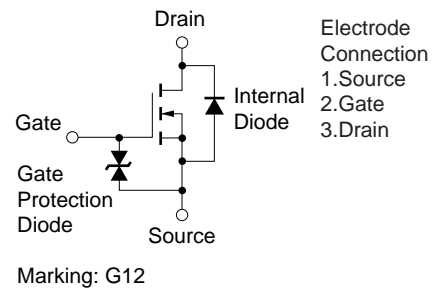
ABSOLUTE MAXIMUM RATINGS (T_A = 25°C)

Drain to Source Voltage	V _{DSS}	50	V
★ Gate to Source Voltage	V _{GSS}	±7.0	V
Drain Current (DC)	I _{D(DC)}	±100	mA
Drain Current (pulse) ^{Note}	I _{D(pulse)}	±200	mA
Total Power Dissipation	P _T	200	mW
Channel Temperature	T _{ch}	150	°C
Operating Temperature	T _{opt}	-55 to +80	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Note PW ≤ 10 ms, Duty Cycle ≤ 50 %

Remark Strong electric field, when exposed to this device, can cause destruction of the gate oxide and ultimately degrade the device operation. Steps must be taken to stop generation of static electricity as much as possible, and quickly dissipate it once, when it has occurred.

EQUIVALENT CIRCUIT

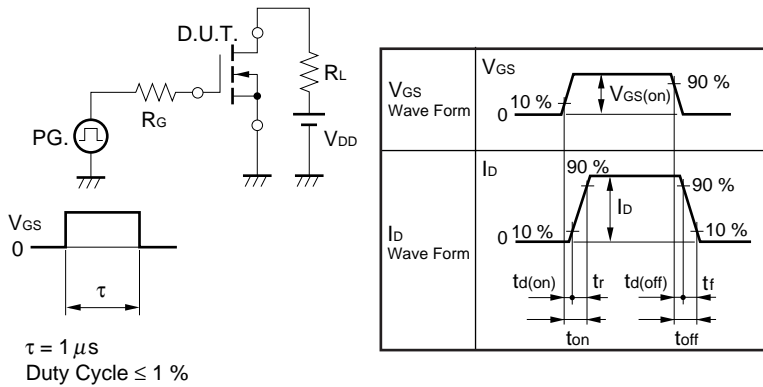


The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

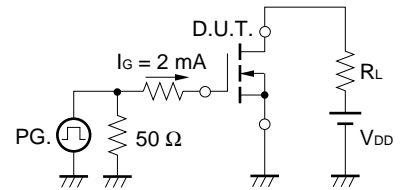
ELECTRICAL CHARACTERISTICS (T_A = 25°C)

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain Cut-off Current	I _{DSS}	V _{DS} = 50 V, V _{GS} = 0 V			10	μA
★ Gate Leakage Current	I _{GSS}	V _{GS} = ±7.0 V, V _{DS} = 0 V			±5.0	μA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 3.0 V, I _D = 1.0 μA	0.9	1.2	1.5	V
Forward Transfer Admittance	y _{fs}	V _{DS} = 3.0 V, I _D = 10 mA	20	38		mS
Drain to Source On-state Resistance	R _{DS(on)1}	V _{GS} = 2.5 V, I _D = 10 mA		22	40	Ω
	R _{DS(on)2}	V _{GS} = 4.0 V, I _D = 10 mA		14	20	Ω
Input Capacitance	C _{iss}	V _{DS} = 3.0 V		8		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V		7		pF
★ Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		3		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 3.0 V		15		ns
Rise Time	t _r	I _D = 20 mA		100		ns
Turn-off Delay Time	t _{d(off)}	V _{GS(on)} = 3.0 V		30		ns
Fall Time	t _f	R _G = 10 Ω, R _L = 150 Ω		35		ns

★ TEST CIRCUIT 1 SWITCHING TIME

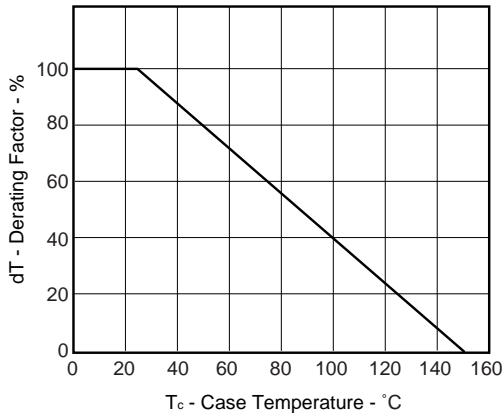


TEST CIRCUIT 2 GATE CHARGE

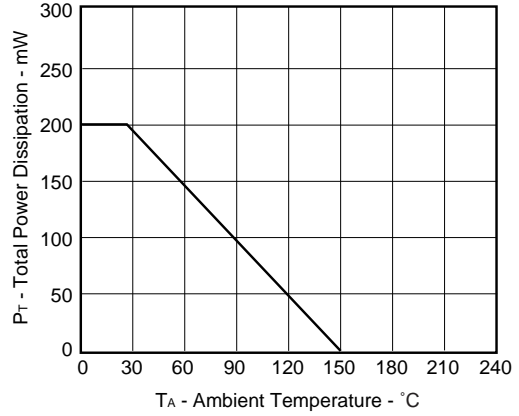


TYPICAL CHARACTERISTICS (T_A = 25°C)

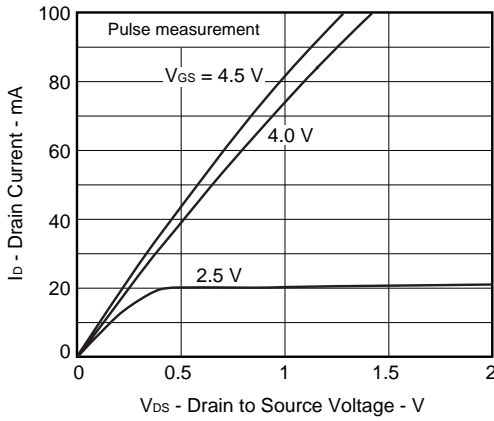
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



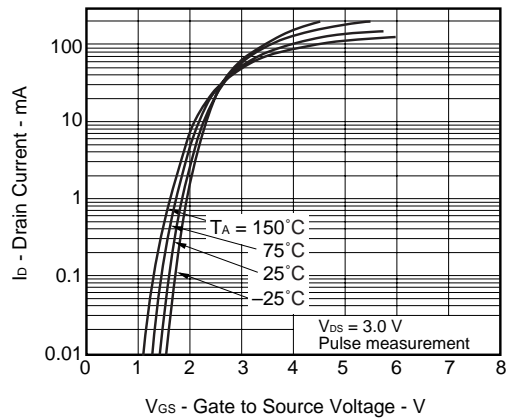
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



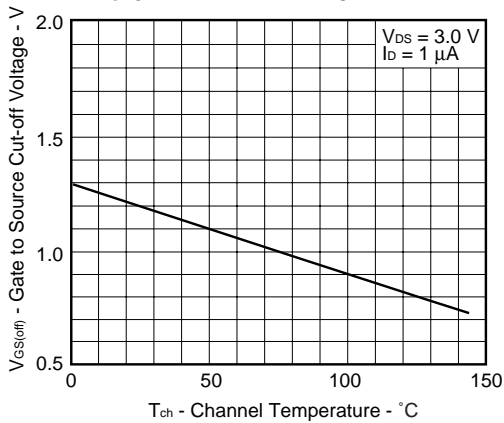
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



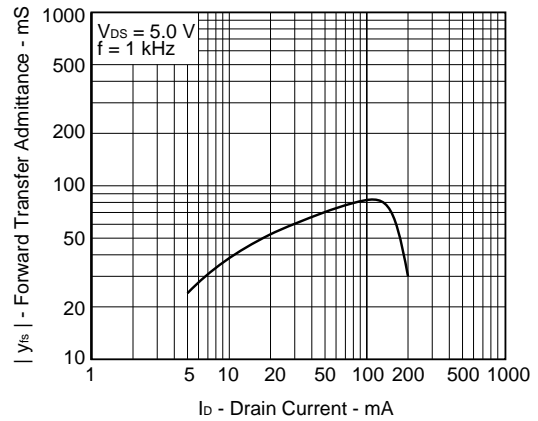
TRANSFER CHARACTERISTICS

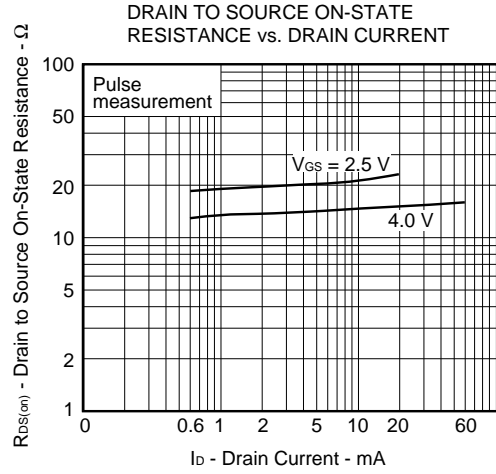
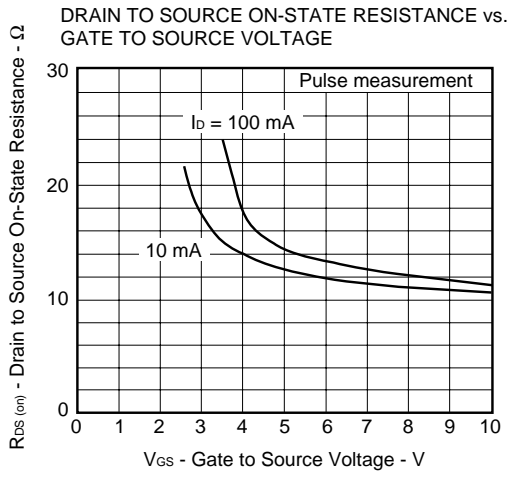


GATE TO SOURCE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT





[MEMO]

[MEMO]

[MEMO]

- **The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.**
 - No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.
 - NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.
 - Descriptions of circuits, software, and other related information in this document are provided for illustrative purposes in semiconductor product operation and application examples. The incorporation of these circuits, software, and information in the design of the customer's equipment shall be done under the full responsibility of the customer. NEC Corporation assumes no responsibility for any losses incurred by the customer or third parties arising from the use of these circuits, software, and information.
 - While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customers must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features.
 - NEC devices are classified into the following three quality grades:
"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.
 - Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
 - Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
 - Specific: Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.
- The quality grade of NEC devices is "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact an NEC sales representative in advance.

This datasheet has been download from:

www.datasheetcatalog.com

Datasheets for electronics components.